PCTEST ENGINEERING LABORATORY, INC.

7185 Oakland Mills Road, Columbia, MD 21046 USA
Tel. 410.290.6652 / Fax 410.290.6654
http://www.pctestlab.com

HEARING AID COMPATIBILITY

Applicant Name:
LG Electronics MobileComm U.S.A. Inc.
1000 Sylvan Avenue
Englewood Cliffs, NJ 07632
United States

Date of Testing:
04/11/2016 - 04/13/2016
Test Site/Location:
PCTEST Lab, Columbia, MD, USA
Test Report Serial No.:
0Y1604120770-R1.ZNF

FCC ID:	**ZNFK550BN**
APPLICANT:	**LG ELECTRONICS MOBILECOMM U.S.A. INC.**

Scope of Test:	RF Emissions Testing
Application Type:	Certification
FCC Rule Part(s):	CFR §20.19(b)
HAC Standard:	ANSI C63.19-2011
EUT Type:	Portable Handset
Model(s):	LG-K550BN, LGK550BN, LG-K550, LGK550, LGMS550, LG-MS550, LG-K550BNGO1, LGK55BNGO1, K550BNGO1
Test Device Serial No.:	*Pre-Production Sample* [S/N: 02042]

C63.19-2011 HAC Category:	**M3 (RF EMISSIONS CATEGORY)**

Note: This revised Test Report (S/N: 0Y1604120770-R1.ZNF) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

Randy Ortanez
President

ACCREDITED
TESTING CERT#2041.01

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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658[1] to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.

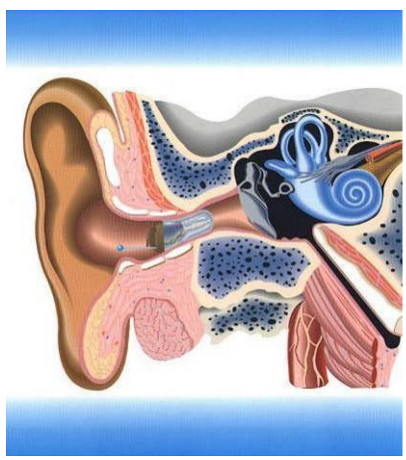


Figure 1-1 Hearing Aid *in-vitu*

[1] FCC Rule & Order, WT Docket 01-309 RM-8658

2. TEST SITE LOCATION

I. Introduction

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2-1).

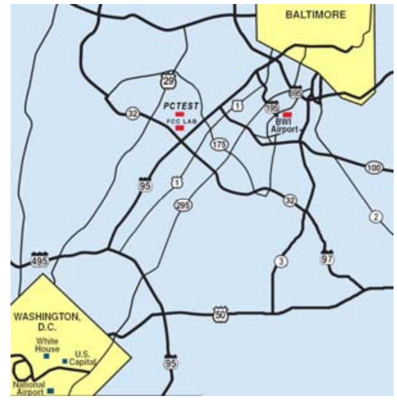


Figure 2-1
Map of the Greater Baltimore and Metropolitan Washington, D.C. area

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in Stonewood Business Center, Guilford Industrial Park, Columbia, Maryland. The site address is 7185 Oakland Mills Road, Columbia, MD 21046. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 10' 24" N latitude and 76° 49' 50" W longitude. The facility is 0.4 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory.

3. EUT DESCRIPTION

FCC ID:	ZNFK550BN
Manufacturer:	LG Electronics MobileComm U.S.A. Inc. 1000 Sylvan Avenue Englewood Cliffs, NJ 07632 United States
Model(s):	LG-K550BN, LGK550BN, LG-K550, LGK550, LGMS550, LG-MS550, LG-K550BNGO1, LGK55BNGO1, K550BNGO1
Serial Number:	02042
Antenna Configurations:	Internal Antenna
HAC Test Configurations:	GSM 850, 128, 190, 251, BT Off, WLAN Off, LTE Off GSM 1900, 512, 661, 810, BT Off, WLAN Off, LTE Off
EUT Type:	Portable Handset

Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Voice over Digital Transport OTT Capability	WIFI Low Power	Additional GSM Power Reduction
GSM	850	VO	Yes	Yes: WIFI or BT	N/A	N/A	No
	1900						
	GPRS/EDGE	DT	No	Yes: WIFI or BT	Yes	N/A	No
UMTS	850	VD	No[1]	Yes: WIFI or BT	N/A	N/A	N/A
	1700						
	1900						
	HSPA	DT	No	Yes: WIFI or BT	Yes	N/A	N/A
LTE (FDD)	700 (B12)	VD[3]	No[1,2]	Yes: WIFI or BT	Yes	N/A	N/A
	850 (B5)						
	1700 (B4)						
	1900 (B2)						
WIFI	2450	VD	No[1,2,4]	Yes: GSM, UMTS, or LTE	Yes	N/A	N/A
	5200						
	5300						
	5500						
	5800						
BT	2450	DT	No	Yes: GSM, UMTS, or LTE	N/A	N/A	N/A

Type Transport
VO = Voice Only
DT = Digital Data - Not intended for CMRS Service
VD = CMRS and Data Transport

Notes:
1. Evaluated for MIF and low-power exemption.
2. No associated T-coil measurement has been made in accordance with the guidance issued by OET in KDB publication 285076 D02 T-Coil testing for CMRS IP.
3. The 3GPP VoLTE CMRS service is defined by GSMA in PRD IR.92 for IP Voice Service and Digital Transport.
4. 2.4GHz 802.11b mode was evaluated at reduced power due to independent power reduction mechanisms in held-to-ear scenarios. Detailed descriptions of the mechanisms are included in the operational description.

Table 3-1: ZNFK550BN HAC Air Interfaces

4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters
Near field Category	**E-field emissions CW dB(V/m)**
f < 960 MHz	
M1	50 to 55
M2	45 to 50
M3	40 to 45
M4	< 40
f > 960 MHz	
M1	40 to 45
M2	35 to 40
M3	30 to 35
M4	< 30

Table 4-1
WD near-field categories as defined in ANSI C63.19-2011

5. SYSTEM SPECIFICATIONS

ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges
Calibration:	In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency:	100 MHz to > 6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m (M3 or better device readings fall well below diode compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm

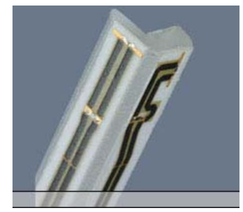
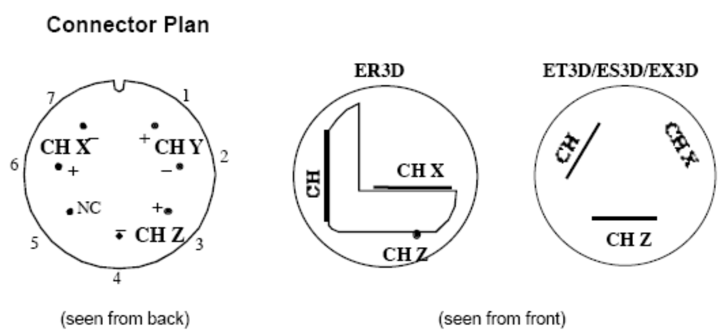


Figure 5-1
E-field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.



The antistatic shielding inside the probe is connected to the probe connector case.

Instrumentation Chain

Equation 1

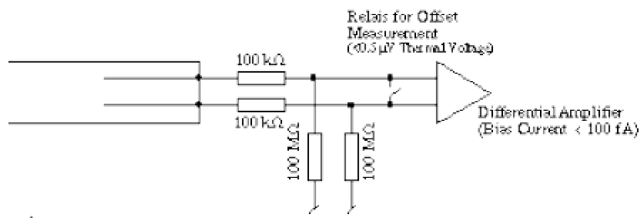
Conversion of Connector Voltage u_i to E-Field E_i

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

E_i:	electric field in V/m
u_i:	voltage of channel i at the connector in µV
$Norm_i$:	sensitivity of channel i in µV/(V/m)^2
ConvF:	enhancement factor in liquid (ConvF=1 for Air)
DCP:	diode compression point in µV
CF:	signal crest factor (peak power/average power)

Conditions of Calibration



Please note:

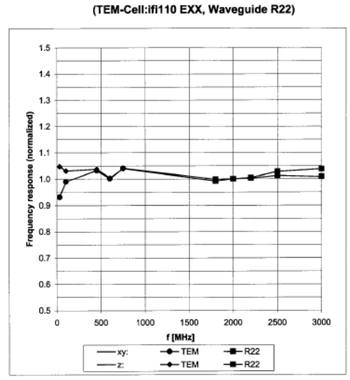
- a lower input impedance of the amplifier will result in different sensitivity factors $Norm_i$ and *DCP*
- larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

Frequency Response of E-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)



Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

Figure 5-2 E-Field Probe Frequency Response

SPEAG Robotic System

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).

Figure 5-3
SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

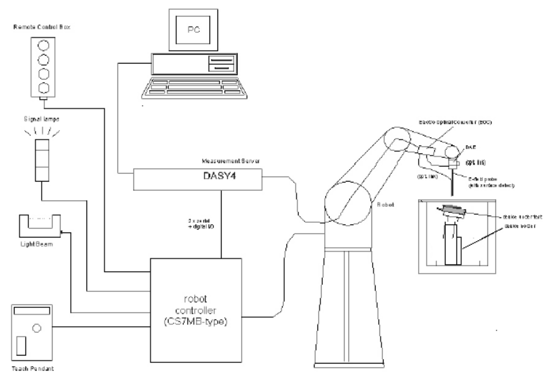


Figure 5-4
SPEAG Robotic System Diagram

DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	U_i	= input signal of channel i	(i = x, y, z)
	cf	= crest factor of exciting field	(DASY parameter)
	dcp_i	= diode compression point	(DASY parameter)

From the compensated input signals the primary field data for each channel can be evaluated:

$$\mathrm{E-fieldprobes:} \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	$Norm_i$	= sensor sensitivity of channel i $\mu V/(V/m)^2$ for E-field Probes	(i = x, y, z)
	$ConvF$	= sensitivity enhancement in solution	
	E_i	= electric field strength of channel i in V/m	

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

6. TEST PROCEDURE

I. RF EMISSIONS

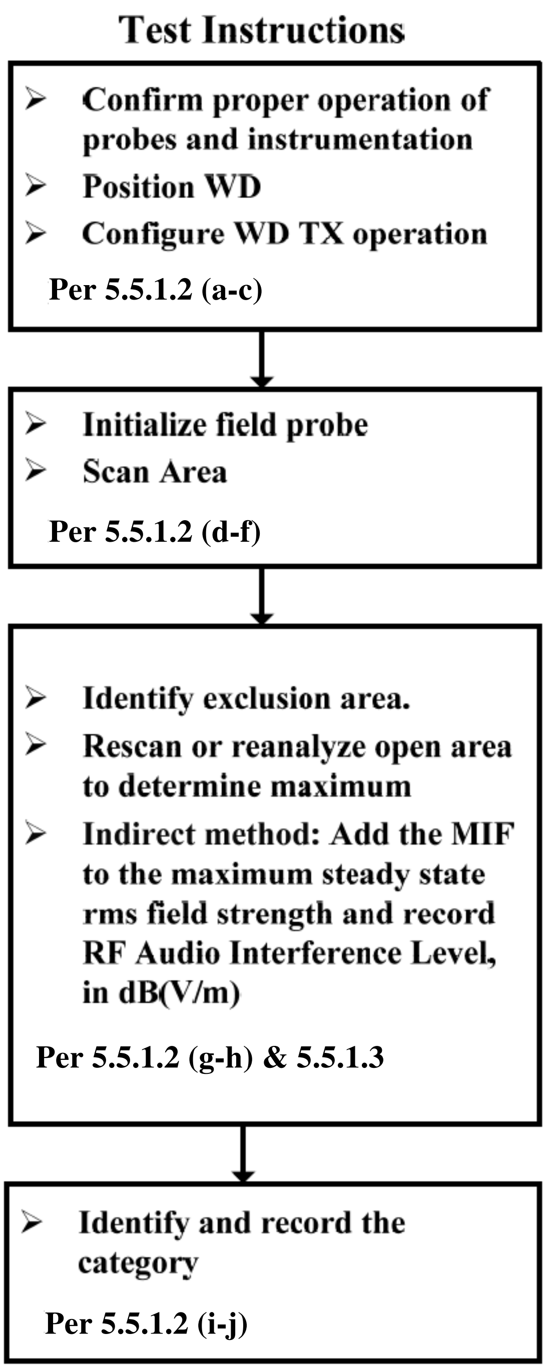


Figure 6-1 RF Emissions Flow Chart

Test Setup

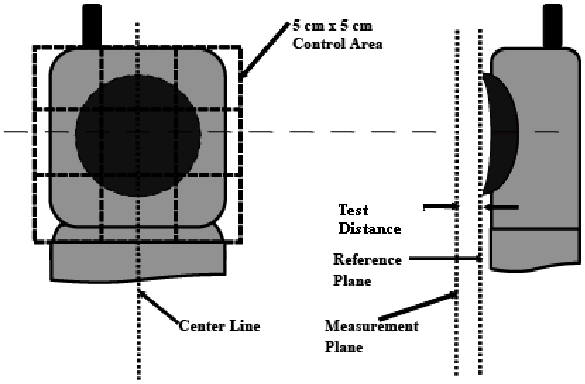


Figure 6-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

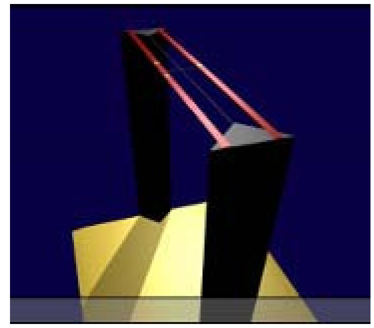


Figure 6-3
HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.

2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.

3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.

4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.

5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.

6. The measurement system measured the field strength at the reference location.

7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360^{o} rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.

8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

7. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:

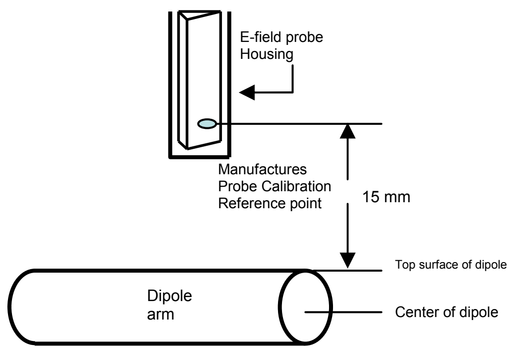


Figure 7-1
Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

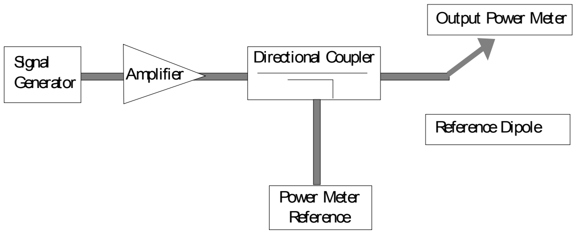


Figure 7-2
Setup for Desired Output Power to Dipole

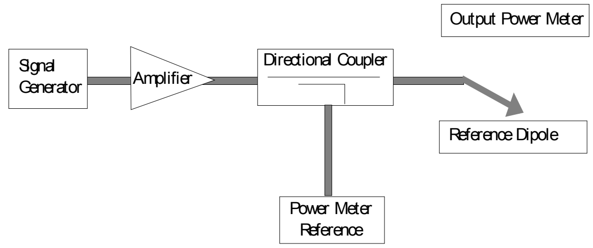


Figure 7-3
Setup to Dipole

Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:

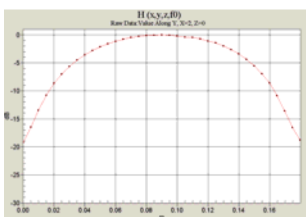


Figure 7-4
2-D Raw Data from scan along dipole axis

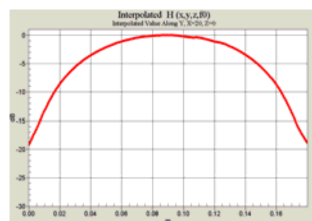


Figure 7-5
2-D Interpolated points from scan along dipole axis

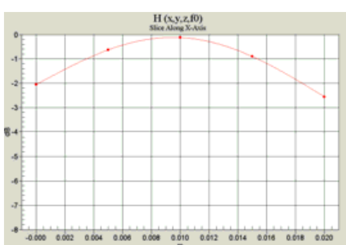


Figure 7-6
2-D Raw Data from scan along transverse axis

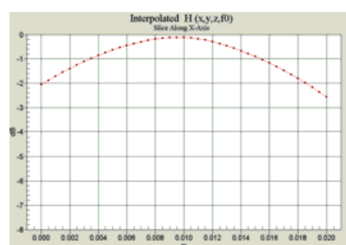


Figure 7-7
2-D Interpolated points from scan along transverse axis

III. System Check Results

Validation Results

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	1003	20.0	107.9	**106.8**	**1.0%**
1880	1137	20.0	89.9	**89.7**	**0.2%**

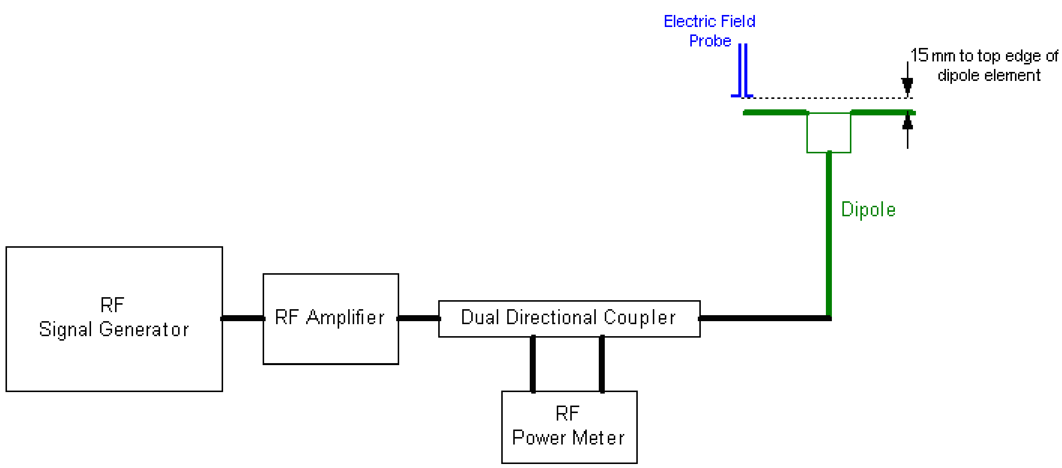


Figure 7-8
System Check Setup

8. MODULATION INTERFERENCE FACTOR

I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
b. Measure the steady-state RMS level at the output of the fast probe or sensor.
c. Measure the steady-state average level at the weighting output.
d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No: 1010:

1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
2. The device was then set to continuously transmit at maximum power.
   Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
3. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
4. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

Audio Interference Level [dB(V/m)] = 20 * log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

II. MIF Measurement Block Diagrams

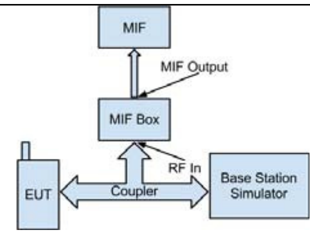


Figure 8-1
MIF Measurement Setup
using a Base Station Simulator

III. Measured Modulation Interference Factors:

Mode	GSM850			GSM1900		
	128	190	251	512	661	810
GSM	3.56	3.56	3.56	3.56	3.55	3.55

Table 8-1
GSM Modulation Interference Factors[1]

Mode		UMTS V			UMTS IV			UMTS II		
		4132	4183	4233	1312	1412	1513	9262	9400	9538
UMTS	12.2 kbps RMC	-24.79	-25.47	-24.79	-25.03	-24.69	-25.02	-25.36	-25.44	-24.86
	12.2 kbps AMR	-15.16	-15.07	-15.28	-14.49	-14.86	-15.37	-14.88	-14.84	-15.07

Table 8-2
UMTS Modulation Interference Factors[1]

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
2	1880	18900	20	16QAM	1	0	-9.56
4	1732.5	20175	20	16QAM	1	0	-9.88
5	836.5	20525	10	16QAM	1	0	-10.66
12	707.5	23095	10	16QAM	1	0	-9.92
2	1880	18900	20	QPSK	1	0	-14.44
2	1880	18900	20	16QAM	1	50	-10.03
2	1880	18900	20	16QAM	1	99	-9.92
2	1880	18900	20	16QAM	50	0	-15.75
2	1880	18900	20	16QAM	100	0	-16.56
2	1880	18900	15	16QAM	1	0	-10.33
2	1880	18900	10	16QAM	1	0	-10.49
2	1880	18900	5	16QAM	1	0	-10.72
2	1880	18900	3	16QAM	1	0	-10.62
2	1880	18900	1.4	16QAM	1	0	-10.57
2	1860	18700	20	16QAM	1	0	-9.61
2	1900	19100	20	16QAM	1	0	-10.04

Table 8-3
LTE Modulation Interference Factors[1 2]

[1] Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

[2] Note: All LTE bands were found to have substantially similar MIF values given similar RB and BW configurations.

Mode	802.11b MIF Measurements [dB]			
	Data Rate [Mbps]			
	1	2	5.5	11
802.11b	-16.21	-15.41	-11.88	-11.77

Table 8-4
802.11b (2.4GHz) Modulation Interference Factors[1,2]

Mode	802.11g MIF Measurements [dB]							
	Data Rate [Mbps]							
	6	9	12	18	24	36	48	54
802.11g	-14.16	-13.59	-13.19	-12.47	-11.96	-11.58	-11.76	-11.99

Table 8-5
802.11g (2.4GHz) Modulation Interference Factors[1,2]

Mode	802.11n (2.4GHz) MIF Measurements [dB]							
	Data Rate [Mbps]							
	6.5	13	19.5	26	39	52	58.5	65
802.11n	-13.91	-12.68	-12.13	-11.66	-11.39	-11.66	-11.92	-12.10

Table 8-6
802.11n (2.4GHz) Modulation Interference Factors[1,2]

Mode	802.11a MIF Measurements [dB]							
	Data Rate [Mbps]							
	6	9	12	18	24	36	48	54
802.11a	-13.86	-13.25	-12.82	-12.19	-11.70	-11.40	-11.57	-11.83

Table 8-7
802.11a (5GHz, 20MHz BW) Modulation Interference Factors[1,2]

Mode	20MHz BW 802.11n (5GHz) MIF Measurements [dB]							
	Data Rate [Mbps]							
	6.5	13	19.5	26	39	52	58.5	65
802.11n	-13.65	-12.47	-11.97	-11.57	-11.35	-11.61	-11.89	-12.07

Table 8-8
802.11n (5GHz, 20MHz BW) Modulation Interference Factors[1,2]

Mode	20MHz BW 802.11ac (5GHz) MIF Measurements [dB]								
	Data Rate [Mbps]								
	6.5	13	19.5	26	39	52	58.5	65	78
802.11ac	-12.84	-11.79	-11.62	-11.50	-12.43	-12.91	-13.35	-13.82	-14.07

Table 8-9
802.11ac (5GHz, 20MHz BW) Modulation Interference Factors[1,2]

[1] Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

[2] Note: WLAN MIF values were found to be independent of the transmit channel.

Mode	40MHz BW 802.11n (5GHz) MIF Measurements [dB]							
	Data Rate [Mbps]							
	13.5	27	40.5	54	81	108	121.5	135
802.11n	-12.54	-11.37	-10.91	-10.84	-11.28	-12.06	-12.57	-12.91

Table 8-10
802.11n (5GHz, 40MHz BW) Modulation Interference Factors[1,2]

Mode	40MHz BW 802.11ac (5GHz) MIF Measurements [dB]									
	Data Rate [Mbps]									
	13.5	27	40.5	54	81	108	121.5	135	162	180
802.11ac	-10.83	-10.73	-11.75	-12.55	-13.57	-14.18	-14.63	-14.85	-15.06	-15.27

Table 8-11
802.11ac (5GHz, 40MHz BW) Modulation Interference Factors[1,2]

Mode	80MHz BW 802.11ac (5GHz) MIF Measurements [dB]									
	Data Rate [Mbps]									
	29.3	58.5	87.8	117	175.5	234	263.3	292.5	351	390
802.11ac	-11.21	-13.06	-14.08	-14.82	-15.50	-16.06	-16.40	-16.28	-16.39	-16.87

Table 8-12
802.11ac (5GHz, 80MHz BW) Modulation Interference Factors[1,2]

[1] Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

[2] Note: WLAN MIF values were found to be independent of the transmit channel.

9. RF CONDUCTED POWER MEASUREMENTS

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator.

II. HAC Measurement Conditions

Output Power Verification
Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces. See Table 9-1 for air interface specific settings of transmit power parameters.

Air Interface:	Parameter Name:	Parameter Set To:
GSM	PCL	GSM850: “5”; GSM1900: “0”
UMTS	TPC	“All 1’s”
LTE	TPC	“Max Power”
WLAN	N/A	Mfr Specified

Table 9-1
Power Control Parameters and Settings by Air Interface

III. Setup Used to Measure RF Conducted Powers

Power measurements were performed using a base station simulator under digital average power.

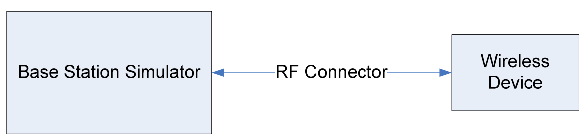


Figure 9-1
Power Measurement Setup

IV. GSM Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)
GSM 850	128	33.51
	190	33.57
	251	33.56
GSM 1900	512	30.30
	661	30.48
	810	30.51

V. UMTS Conducted Powers

Mode	Cellular Band [dBm]			AWS Band [dBm]			PCS Band [dBm]		
	4132	4183	4233	1312	1412	1513	9262	9400	9538
12.2 kbps RMC	23.68	23.55	23.60	24.53	24.54	24.51	24.50	24.56	24.47
12.2 kbps AMR	23.65	23.51	23.65	24.57	24.52	24.52	24.44	24.45	24.48

VI. LTE Conducted Powers

Table 9-2
LTE Band 12 (707.5MHz) Conducted Powers - 10 MHz Bandwidth

Modulation	RB Size	RB Offset	Mid Channel 23095 (707.5 MHz) Conducted Power [dBm]	MPR Allowed per 3GPP [dB]	MPR [dB]
QPSK	1	0	24.70	0	0
	1	25	24.55		0
	1	49	24.38		0
	25	0	23.27	0-1	1
	25	12	23.21		1
	25	25	23.18		1
	50	0	23.17		1
16QAM	1	0	23.43	0-1	1
	1	25	23.40		1
	1	49	23.10		1
	25	0	22.48	0-2	2
	25	12	22.34		2
	25	25	22.39		2
	50	0	22.36		2

Note: Since LTE Band 12 at 10MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 9-3
LTE Band 12 (707.5MHz) Conducted Powers - 5 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 23035 (701.5 MHz) Conducted Power [dBm]	Mid Channel 23095 (707.5 MHz) Conducted Power [dBm]	High Channel 23155 (713.5 MHz) Conducted Power [dBm]	MPR Allowed per 3GPP [dB]	MPR [dB]
QPSK	1	0	24.47	24.43	24.31	0	0
	1	12	24.70	24.70	24.58		0
	1	24	24.62	24.49	24.39		0
	12	0	23.20	23.51	23.23	0-1	1
	12	6	23.26	23.67	23.36		1
	12	13	23.31	23.44	23.39		1
	25	0	23.21	23.45	23.30		1
16QAM	1	0	22.95	23.05	23.01	0-1	1
	1	12	23.48	23.61	23.11		1
	1	24	23.10	23.07	23.14		1
	12	0	22.28	22.36	22.22	0-2	2
	12	6	22.10	22.55	22.44		2
	12	13	22.13	22.45	22.49		2
	25	0	22.29	22.43	22.59		2

Table 9-4
LTE Band 12 (707.5MHz) Conducted Powers - 3 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 23025 (700.5 MHz)	Mid Channel 23095 (707.5 MHz)	High Channel 23165 (714.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.53	24.34	24.24	0	0
	1	7	24.49	24.56	24.45		0
	1	14	24.25	24.21	24.32		0
	8	0	23.30	23.27	23.37	0-1	1
	8	4	23.26	23.45	23.39		1
	8	7	23.27	23.39	23.29		1
	15	0	23.26	23.22	23.33		1
16QAM	1	0	23.08	22.93	23.10	0-1	1
	1	7	23.03	23.56	23.59		1
	1	14	23.05	23.09	23.03		1
	8	0	22.56	22.06	22.26	0-2	2
	8	4	22.58	22.51	22.35		2
	8	7	22.60	22.25	22.29		2
	15	0	22.43	22.55	22.50		2

Table 9-5
LTE Band 12 (707.5MHz) Conducted Powers – 1.4 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 23017 (699.7 MHz)	Mid Channel 23095 (707.5 MHz)	High Channel 23173 (715.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.55	24.44	24.47	0	0
	1	2	24.41	24.29	24.49		0
	1	5	24.36	24.28	24.48		0
	3	0	24.07	24.34	24.36		0
	3	2	24.24	24.42	24.33		0
	3	3	24.32	24.39	24.29		0
	6	0	23.24	23.51	23.24	0-1	1
16QAM	1	0	23.06	22.87	22.93	0-1	1
	1	2	23.22	23.22	22.98		1
	1	5	22.97	23.09	23.11		1
	3	0	23.48	23.38	23.46		1
	3	2	23.54	23.61	23.56		1
	3	3	23.31	23.51	23.48		1
	6	0	22.39	22.28	22.43	0-2	2

Table 9-6
LTE Band 5 (836.5MHz) Conducted Powers - 10 MHz Bandwidth

Modulation	RB Size	RB Offset	Mid Channel 20525 (836.5 MHz) Conducted Power [dBm]	MPR Allowed per 3GPP [dB]	MPR [dB]
QPSK	1	0	23.48	0	0
	1	25	23.60		0
	1	49	23.54		0
	25	0	22.35	0-1	1
	25	12	22.39		1
	25	25	22.31		1
	50	0	22.35		1
16QAM	1	0	22.42	0-1	1
	1	25	22.65		1
	1	49	22.48		1
	25	0	21.39	0-2	2
	25	12	21.43		2
	25	25	21.36		2
	50	0	21.26		2

Note: Since LTE Band 5 at 10MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 9-7
LTE Band 5 (836.5MHz) Conducted Powers - 5 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 20425 (826.5 MHz)	Mid Channel 20525 (836.5 MHz)	High Channel 20625 (846.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	23.47	23.28	23.31	0	0
	1	12	23.56	23.48	23.51		0
	1	24	23.39	23.33	23.44		0
	12	0	22.43	22.32	22.33	0-1	1
	12	6	22.35	22.41	22.35		1
	12	13	22.32	22.33	22.28		1
	25	0	22.39	22.29	22.38		1
16QAM	1	0	22.02	22.01	21.96	0-1	1
	1	12	21.91	22.41	22.29		1
	1	24	21.88	22.11	22.03		1
	12	0	21.16	21.23	21.34	0-2	2
	12	6	21.19	21.22	21.33		2
	12	13	21.22	21.18	21.34		2
	25	0	21.33	21.35	21.36		2

Table 9-8
LTE Band 5 (836.5MHz) Conducted Powers - 3 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 20415 (825.5 MHz)	Mid Channel 20525 (836.5 MHz)	High Channel 20635 (847.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	23.39	23.36	23.41	0	0
	1	7	23.49	23.35	23.47		0
	1	14	23.42	23.33	23.44		0
	8	0	22.46	22.33	22.34	0-1	1
	8	4	22.45	22.34	22.35		1
	8	7	22.38	22.34	22.37		1
	15	0	22.37	22.29	22.31		1
16QAM	1	0	22.06	22.04	22.08	0-1	1
	1	7	22.24	22.26	22.23		1
	1	14	22.14	21.96	22.05		1
	8	0	21.22	21.16	21.17	0-2	2
	8	4	21.17	21.15	21.22		2
	8	7	21.24	21.24	21.23		2
	15	0	21.48	21.32	21.32		2

Table 9-9
LTE Band 5 (836.5MHz) Conducted Powers – 1.4 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 20407 (824.7 MHz)	Mid Channel 20525 (836.5 MHz)	High Channel 20643 (848.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	23.47	23.29	23.47	0	0
	1	2	23.48	23.39	23.54		0
	1	5	23.37	23.35	23.48		0
	3	0	23.37	23.27	23.36		0
	3	2	23.36	23.39	23.41		0
	3	3	23.33	23.38	23.39		0
	6	0	22.38	22.37	22.34	0-1	1
16QAM	1	0	22.02	21.99	22.02	0-1	1
	1	2	22.11	22.15	22.16		1
	1	5	21.99	21.96	21.95		1
	3	0	22.56	22.56	22.52		1
	3	2	22.63	22.59	22.58		1
	3	3	22.51	22.48	22.42		1
	6	0	21.41	21.23	21.32	0-2	2

Table 9-10
LTE Band 4 (1732.5MHz) Conducted Powers – 20 MHz Bandwidth

Modulation	RB Size	RB Offset	Mid Channel 20175 (1732.5 MHz) Conducted Power [dBm]	MPR Allowed per 3GPP [dB]	MPR [dB]
QPSK	1	0	24.31	0	0
	1	50	24.49		0
	1	99	24.14		0
	50	0	23.05	0-1	1
	50	25	23.07		1
	50	50	23.00		1
	100	0	23.02		1
16QAM	1	0	23.10	0-1	1
	1	50	23.11		1
	1	99	23.25		1
	50	0	22.21	0-2	2
	50	25	22.23		2
	50	50	22.07		2
	100	0	22.08		2

Note: Since LTE Band 4 at 20MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 9-11
LTE Band 4 (1732.5MHz) Conducted Powers – 15 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 20025 (1717.5 MHz)	Mid Channel 20175 (1732.5 MHz)	High Channel 20325 (1747.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.30	24.04	24.39	0	0
	1	36	24.21	24.21	24.11		0
	1	74	24.31	24.15	24.17		0
	36	0	23.03	23.02	23.10	0-1	1
	36	18	23.00	23.08	23.09		1
	36	37	22.98	23.01	23.02		1
	75	0	23.05	23.01	23.01		1
16QAM	1	0	23.03	23.13	23.38	0-1	1
	1	36	23.11	23.04	23.11		1
	1	74	23.15	23.05	23.29		1
	36	0	22.01	22.02	22.01	0-2	2
	36	18	22.17	22.13	22.19		2
	36	37	21.97	22.02	22.01		2
	75	0	22.05	22.00	22.14		2

Table 9-12
LTE Band 4 (1732.5MHz) Conducted Powers – 10 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 20000 (1715.0 MHz)	Mid Channel 20175 (1732.5 MHz)	High Channel 20350 (1750.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.18	24.36	24.18	0	0
	1	25	24.29	24.24	24.56		0
	1	49	24.07	24.14	24.31		0
	25	0	23.00	23.07	23.10	0-1	1
	25	12	23.08	23.14	23.16		1
	25	25	23.07	23.03	23.13		1
	50	0	23.02	23.10	23.19		1
16QAM	1	0	23.26	23.07	23.25	0-1	1
	1	25	23.37	23.25	23.04		1
	1	49	23.13	23.09	23.38		1
	25	0	22.01	22.21	22.21	0-2	2
	25	12	22.11	22.31	22.39		2
	25	25	22.12	22.00	22.21		2
	50	0	22.00	22.18	22.13		2

Table 9-13
LTE Band 4 (1732.5MHz) Conducted Powers – 5 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel	Mid Channel	High Channel	MPR Allowed per 3GPP [dB]	MPR [dB]
			19975 (1712.5 MHz)	20175 (1732.5 MHz)	20375 (1752.5 MHz)		
			Conducted Power [dBm]				
QPSK	1	0	24.04	24.18	24.23	0	0
	1	12	24.10	24.40	24.24		0
	1	24	24.04	24.13	24.46		0
	12	0	23.06	23.13	23.13	0-1	1
	12	6	23.00	23.10	23.12		1
	12	13	23.06	23.01	23.21		1
	25	0	23.04	23.03	23.09		1
16QAM	1	0	23.03	23.17	23.15	0-1	1
	1	12	23.29	23.27	23.50		1
	1	24	23.08	23.08	23.31		1
	12	0	22.09	22.08	22.04	0-2	2
	12	6	22.05	22.15	22.06		2
	12	13	22.06	22.06	22.14		2
	25	0	22.08	22.14	22.19		2

Table 9-14
LTE Band 4 (1732.5MHz) Conducted Powers – 3 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel	Mid Channel	High Channel	MPR Allowed per 3GPP [dB]	MPR [dB]
			19965 (1711.5 MHz)	20175 (1732.5 MHz)	20385 (1753.5 MHz)		
			Conducted Power [dBm]				
QPSK	1	0	24.10	24.18	24.12	0	0
	1	7	24.17	24.24	24.22		0
	1	14	24.04	24.07	24.30		0
	8	0	23.17	23.23	23.12	0-1	1
	8	4	23.02	23.25	23.11		1
	8	7	23.07	23.20	23.06		1
	15	0	23.08	23.03	23.09		1
16QAM	1	0	23.07	23.18	23.05	0-1	1
	1	7	23.20	23.45	23.26		1
	1	14	23.01	23.16	23.21		1
	8	0	22.07	22.13	22.07	0-2	2
	8	4	22.01	22.08	22.07		2
	8	7	22.06	22.04	22.00		2
	15	0	22.13	22.18	22.11		2

Table 9-15
LTE Band 4 (1732.5MHz) Conducted Powers – 1.4 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel	Mid Channel	High Channel	MPR Allowed per 3GPP [dB]	MPR [dB]
			19957 (1710.7 MHz)	20175 (1732.5 MHz)	20393 (1754.3 MHz)		
			Conducted Power [dBm]				
QPSK	1	0	24.17	24.33	24.36	0	0
	1	2	24.25	24.39	24.34		0
	1	5	24.16	24.22	24.32		0
	3	0	24.07	24.25	24.09		0
	3	2	24.12	24.19	24.29		0
	3	3	24.07	24.12	24.22		0
	6	0	23.10	23.22	23.14	0-1	1
16QAM	1	0	23.07	23.24	23.18	0-1	1
	1	2	23.24	23.38	23.34		1
	1	5	23.01	23.08	23.28		1
	3	0	23.48	23.42	23.35		1
	3	2	23.45	23.28	23.49		1
	3	3	23.39	23.18	23.34		1
	6	0	22.19	22.27	22.46	0-2	2

Table 9-16
LTE Band 2 (1880.0MHz) Conducted Powers – 20 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 18700 (1860.0 MHz)	Mid Channel 18900 (1880.0 MHz)	High Channel 19100 (1900.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.37	24.40	24.35	0	0
	1	50	24.70	24.62	24.39		0
	1	99	24.32	24.43	24.27		0
	50	0	23.33	23.10	23.19	0-1	1
	50	25	23.25	23.20	23.10		1
	50	50	23.20	23.15	23.09		1
	100	0	23.21	23.09	23.19		1
16QAM	1	0	23.23	23.24	23.22	0-1	1
	1	50	23.38	23.37	23.12		1
	1	99	22.97	23.05	23.05		1
	50	0	22.24	22.11	22.23	0-2	2
	50	25	22.26	22.25	22.11		2
	50	50	22.41	22.13	22.02		2
	100	0	22.22	22.16	22.23		2

Table 9-17
LTE Band 2 (1880.0MHz) Conducted Powers – 15 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 18675 (1857.5 MHz)	Mid Channel 18900 (1880.0 MHz)	High Channel 19125 (1902.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.49	24.41	24.41	0	0
	1	36	24.50	24.33	24.38		0
	1	74	24.38	24.39	24.43		0
	36	0	23.22	23.20	23.21	0-1	1
	36	18	23.29	23.26	23.29		1
	36	37	23.17	23.28	23.19		1
	75	0	23.17	23.23	23.14		1
16QAM	1	0	23.44	23.09	23.40	0-1	1
	1	36	23.35	23.19	23.23		1
	1	74	23.29	23.34	23.04		1
	36	0	22.37	22.46	22.36	0-2	2
	36	18	22.42	22.30	22.33		2
	36	37	22.45	22.34	22.30		2
	75	0	22.31	22.31	22.24		2

Table 9-18
LTE Band 2 (1880.0MHz) Conducted Powers – 10 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel 18650 (1855.0 MHz)	Mid Channel 18900 (1880.0 MHz)	High Channel 19150 (1905.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]				
QPSK	1	0	24.56	24.42	24.26	0	0
	1	25	24.45	24.46	24.34		0
	1	49	24.44	24.35	24.33		0
	25	0	23.31	23.24	23.13	0-1	1
	25	12	23.30	23.24	23.23		1
	25	25	23.15	23.19	23.03		1
	50	0	23.27	23.20	23.10		1
16QAM	1	0	23.12	23.29	23.36	0-1	1
	1	25	23.28	23.21	23.16		1
	1	49	23.18	23.13	23.19		1
	25	0	22.45	22.47	22.19	0-2	2
	25	12	22.40	22.38	22.37		2
	25	25	22.25	22.23	22.31		2
	50	0	22.32	22.37	22.31		2

Table 9-19
LTE Band 2 (1880.0MHz) Conducted Powers – 5 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel	Mid Channel	High Channel	MPR Allowed per 3GPP [dB]	MPR [dB]
			18625 (1852.5 MHz)	18900 (1880.0 MHz)	19175 (1907.5 MHz)		
			Conducted Power [dBm]				
QPSK	1	0	24.35	24.37	24.27	0	0
	1	12	24.55	24.47	24.42		0
	1	24	24.29	24.34	24.29		0
	12	0	23.37	23.19	23.24	0-1	1
	12	6	23.36	23.28	23.27		1
	12	13	23.21	23.28	23.15		1
	25	0	23.36	23.25	23.18		1
16QAM	1	0	23.42	23.15	23.26	0-1	1
	1	12	23.29	23.22	23.32		1
	1	24	23.23	23.43	23.22		1
	12	0	22.18	22.33	22.03	0-2	2
	12	6	22.12	22.18	22.34		2
	12	13	22.21	22.27	22.24		2
	25	0	22.25	22.36	22.23		2

Table 9-20
LTE Band 2 (1880.0MHz) Conducted Powers – 3 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel	Mid Channel	High Channel	MPR Allowed per 3GPP [dB]	MPR [dB]
			18615 (1851.5 MHz)	18900 (1880.0 MHz)	19185 (1908.5 MHz)		
			Conducted Power [dBm]				
QPSK	1	0	24.41	24.35	24.37	0	0
	1	7	24.53	24.37	24.52		0
	1	14	24.48	24.32	24.26		0
	8	0	23.38	23.26	23.20	0-1	1
	8	4	23.43	23.30	23.19		1
	8	7	23.31	23.28	23.27		1
	15	0	23.30	23.28	23.16		1
16QAM	1	0	23.06	23.16	23.24	0-1	1
	1	7	23.16	23.29	23.22		1
	1	14	23.13	23.26	23.35		1
	8	0	22.25	22.22	22.29	0-2	2
	8	4	22.36	22.16	22.21		2
	8	7	22.27	22.13	22.26		2
	15	0	22.36	22.17	22.37		2

Table 9-21
LTE Band 2 (1880.0MHz) Conducted Powers – 1.4 MHz Bandwidth

Modulation	RB Size	RB Offset	Low Channel	Mid Channel	High Channel	MPR Allowed per 3GPP [dB]	MPR [dB]
			18607 (1850.7 MHz)	18900 (1880.0 MHz)	19193 (1909.3 MHz)		
			Conducted Power [dBm]				
QPSK	1	0	24.30	24.40	24.22	0	0
	1	2	24.60	24.36	24.29		0
	1	5	24.47	24.32	24.32		0
	3	0	24.36	24.22	24.18		0
	3	2	24.41	24.25	24.23		0
	3	3	24.38	24.30	24.23		0
	6	0	23.35	23.24	23.19	0-1	1
16QAM	1	0	23.31	23.26	23.27	0-1	1
	1	2	23.19	23.53	23.26		1
	1	5	23.26	23.20	23.10		1
	3	0	23.48	23.58	23.41		1
	3	2	23.63	23.58	23.49		1
	3	3	23.41	23.36	23.32		1
	6	0	22.36	22.32	22.25	0-2	2

VII. WLAN Conducted Powers

Table 9-22
IEEE 802.11b/g/n (2.4GHz) Average RF Power

Freq [MHz]	Channel	2.4GHz Conducted Power [dBm]		
		IEEE Transmission Mode		
		802.11b	802.11g	802.11n
2412	1	18.49	17.53	13.13
2437	6	17.94	18.01	13.70
2462	11	17.76	17.14	13.11

*This device utilizes independent power reduction mechanisms for the WLAN transmitter in 2.4GHz 802.11b modes for held-to-ear scenarios.

Table 9-23
IEEE 802.11a/n/ac (5GHz, 20MHz BW) Average RF Power

Freq [MHz]	Channel	5GHz (20MHz) Conducted Power [dBm]		
		IEEE Transmission Mode		
		802.11a	802.11n	802.11ac
5180	36	13.81	13.85	9.62
5200	40	16.88	13.77	9.97
5220	44	13.84	12.79	9.84
5240	48	13.89	12.96	9.82
5260	52	13.90	12.88	9.88
5280	56	16.96	13.05	10.00
5300	60	13.95	12.97	9.71
5320	64	13.78	12.95	9.23
5500	100	13.58	13.22	9.65
5580	116	13.56	13.36	9.48
5660	132	13.46	12.45	9.24
5700	140	13.27	13.41	9.48
5745	149	13.25	12.48	9.48
5785	157	16.71	12.79	9.88
5825	165	13.72	12.86	9.83

Table 9-24
IEEE 802.11n/ac (5GHz, 40MHz BW) Average RF Power

Freq [MHz]	Channel	5GHz (40MHz) Conducted Power [dBm] IEEE Transmission Mode	
		802.11n	802.11ac
5190	38	9.84	10.31
5230	46	9.96	10.46
5270	54	10.02	10.18
5310	62	9.31	9.82
5510	102	10.45	10.03
5550	110	10.67	9.87
5670	134	10.62	9.74
5755	151	9.57	9.85
5795	159	9.88	10.12

Table 9-25
IEEE 802.11ac (5GHz, 80MHz BW) Average RF Power

5GHz (80MHz) Conducted Power [dBm]		
Freq [MHz]	Channel	IEEE Transmission Mode
		802.11ac
5210	42	6.56
5290	58	6.52
5530	106	6.55
5610	122	6.47
5690	138	7.17
5775	155	6.43

10. JUSTIFICATION OF HELD TO EAR MODES TESTED

I. Analysis of RF Air Interface Technologies

a. According to the April 2013 TCB workshop slides, OTT data services are outside the current definition of a managed CMRS service and are currently not required to be evaluated.

b. No associated T-coil measurements for VoLTE or VoIP over WIFI CMRS have been made in accordance with the guidance issued by OET in KDB publication 285076 D02 T-Coil testing for CMRS IP.

c. An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes.

The worst case MIF plus the worst case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

II. Individual Mode Evaluations

Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
GSM850	24.54*	3.56	28.10	Yes
GSM1900	21.48*	3.56	25.04	Yes
UMTS - RMC	24.56	-24.69	-0.13	No
UMTS - AMR	24.57	-14.49	10.08	No
LTE - FDD	24.70	-9.56	15.14	No
2.4GHz WLAN	18.49	-11.39	7.10	No
5GHz WLAN	16.96	-10.73	6.23	No

Table 10-1
Max Power + MIF calculations
for Low Power Exemptions

* Note: C63.19 Footnote 20 (pg.13) indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.

III. Low-Power Exemption Conclusions

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for all GSM voice modes. All other air interfaces are exempt.

11. OVERALL MEASUREMENT SUMMARY

FCC ID:	ZNFK550BN
Model:	LG-K550BN, LGK550BN, LG-K550, LGK550, LGMS550, LG-MS550, LG-K550BNGO1, LGK55BNGO1, K550BNGO1
S/N:	02042

I. E-FIELD EMISSIONS:

Table 11-1
HAC Data Summary for E-field

Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 5.5
E-field Emissions											
GSM850	128	Acoustic	33.51	42.41	32.55	3.56	36.11	45.00	-8.89	M4	none
GSM850	190	Acoustic	33.57	46.57	33.36	3.56	36.92	45.00	-8.08	M4	none
GSM850	251	Acoustic	33.56	55.73	34.92	3.56	38.48	45.00	-6.52	M4	none
GSM1900	512	Acoustic	30.30	26.26	28.39	3.56	31.95	35.00	-3.05	M3	none
GSM1900	661	Acoustic	30.48	26.27	28.39	3.55	31.94	35.00	-3.06	M3	none
GSM1900	810	Acoustic	30.51	22.09	26.88	3.55	30.43	35.00	-4.57	M3	none
GSM1900	512	T-coil	30.30	26.26	28.39	3.56	31.95	35.00	-3.05	M3	none

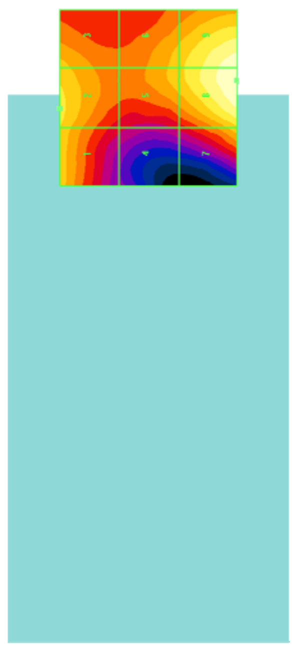


Figure 11-1
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

II. Worst-case Configuration Evaluation

Table 11-2
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
Probe Rotation at Worst-Case									
GSM1900	512	Acoustic	26.58	28.49	3.56	32.05	**35.00**	-2.95	M3

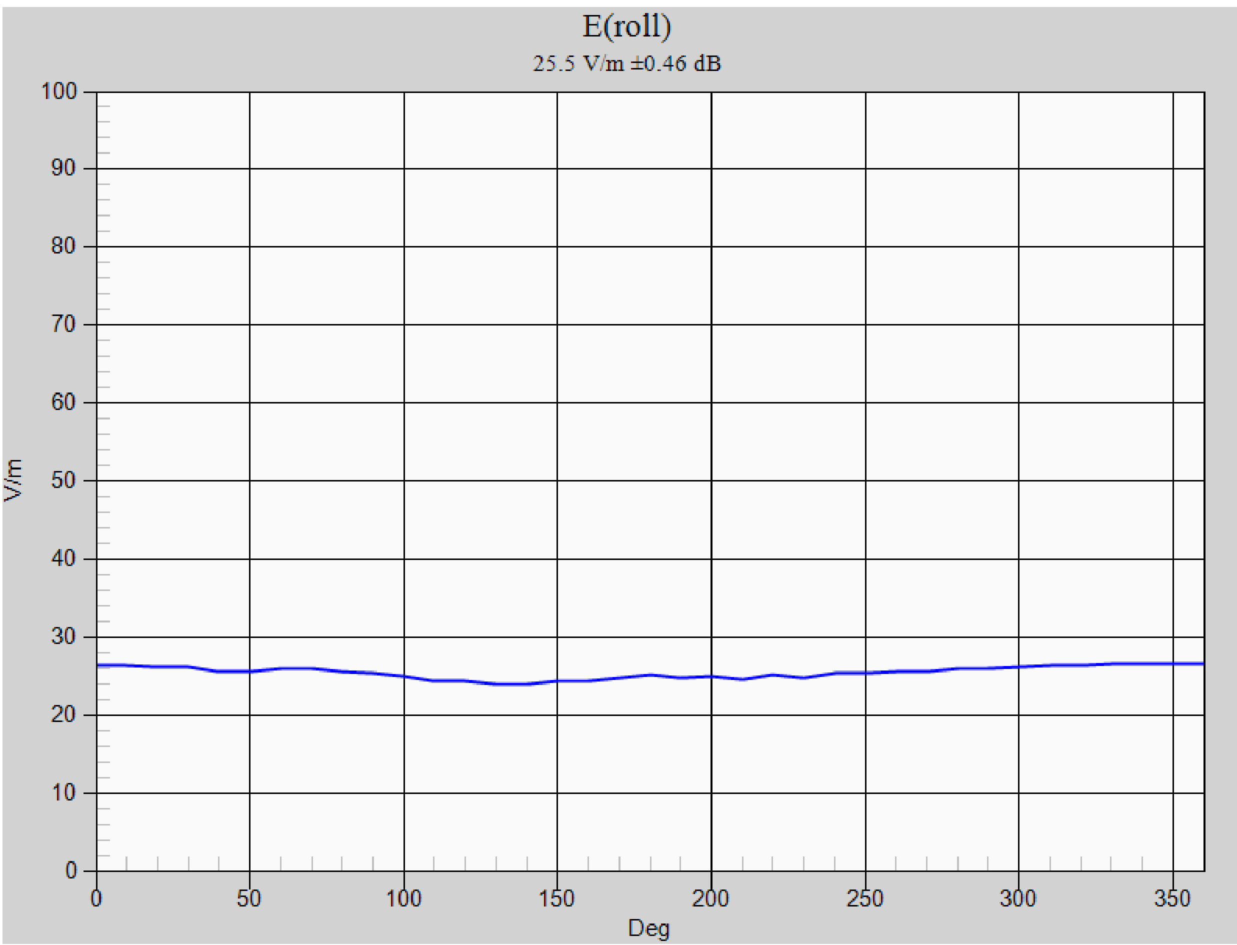


Figure 11-2
Worst-Case Probe Rotation about Azimuth axis

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

12. EQUIPMENT LIST

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4438C	ESG Vector Signal Generator	3/4/2015	Biennial	3/4/2017	MY45090555
Agilent	N5182A	MXG Vector Signal Generator	11/6/2015	Annual	11/6/2016	MY47420603
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	ML2495A	Power Meter	10/16/2015	Biennial	10/16/2017	941001
Anritsu	MA2411B	Pulse Power Sensor	10/14/2015	Biennial	10/14/2017	846215
Anritsu	MA24106A	USB Power Sensor	5/29/2015	Annual	5/29/2016	1244512
Anritsu	MA24106A	USB Power Sensor	5/29/2015	Annual	5/29/2016	1248508
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Pasternack	NC-100	Torque Wrench	5/21/2015	Biennial	5/21/2017	N/A
Rohde & Schwarz	CMW500	Radio Communication Tester	7/21/2015	Annual	7/21/2016	116743
Rohde & Schwarz	CMU200	Base Station Simulator	12/2/2015	Annual	12/2/2016	833855/0010
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/17/2015	Biennial	2/17/2017	1137
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/18/2015	Biennial	2/18/2017	1003
SPEAG	ER3DV6	Freespace E-field Probe	8/24/2015	Annual	8/24/2016	2335
SPEAG	DAE4	Dasy Data Acquisition Electronics	11/11/2015	Annual	11/11/2016	1334

Table 12-1
Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST).

***Note: CBT (Calibrated Before Testing).** Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

13. MEASUREMENT UNCERTAINTY

Wireless Communications Device Near-Field Measurement Uncertainty Estimation							
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System							
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.3%
Expanded Uncertainty [95% confidence]						1.31	32.6%
Expanded Uncertainty [95% confidence] on Field						0.66	16.3%

Table 13-1
Uncertainty Estimation Table

Notes:
1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.
2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

14. TEST DATA

See following Attached Pages for Test Data.

Date: 04/11/2016

PCTEST Hearing-Aid Compatibility Facility

DUT: CD835V3 - SN1003

Type: CD835V3
Serial: 1003

Communication System: CW; Frequency: 835 MHz;

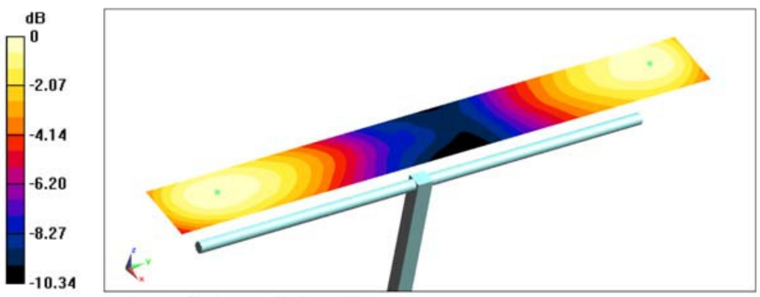
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/24/2015
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1334; Calibrated: 11/11/2015
- Phantom: HAC Test Arch with AMCC, Center; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (8);

835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 106.5 V/m; Power Drift = 0.14 dB
Applied MIF = 0.00 dB
Average Value of Peak (interpolated) = 107.9 V/m



0 dB = 108.3 V/m = 40.69 dBV/m

Date: 04/11/2016

PCTEST Hearing-Aid Compatibility Facility

DUT: CD1880V3 - SN1137

Type: CD1880V3
Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

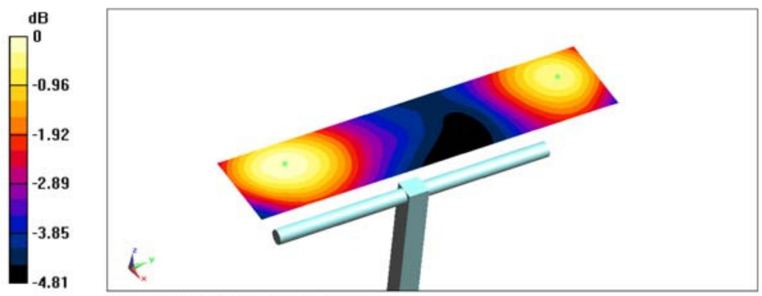
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/24/2015
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn1334; Calibrated: 11/11/2015
- Phantom: HAC Test Arch with AMCC, Center; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (8);

1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 155.6 V/m; Power Drift = -0.17 dB
Applied MIF = 0.00 dB
Average Value of Peak (interpolated) = 89.9 V/m



0 dB = 91.55 V/m = 39.23 dBV/m

PCTEST Hearing-Aid Compatibility Facility

DUT: ZNFK550BN

Type: Portable Handset
Serial: 02042
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 848.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/24/2015
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1334; Calibrated: 11/11/2015
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (8);

GSM850 High Channel /Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 71.84 V/m; Power Drift = 0.14 dB
Applied MIF = 3.56 dB
RF audio interference level = 38.48 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 **M4** **37.92 dBV/m**	Grid 2 **M4** **38.45 dBV/m**	Grid 3 **M4** **37.97 dBV/m**
Grid 4 **M4** **37.85 dBV/m**	Grid 5 **M4** **38.48 dBV/m**	Grid 6 **M4** **37.95 dBV/m**
Grid 7 **M4** **37.65 dBV/m**	Grid 8 **M4** **38.21 dBV/m**	Grid 9 **M4** **37.65 dBV/m**

0 dB = 83.96 V/m = 38.48 dBV/m

PCTEST Hearing-Aid Compatibility Facility

DUT: ZNFK550BN

Type: Portable Handset
Serial: 02042
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1850.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: ER3DV6 - SN2335; Calibrated: 08/24/2015
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1334; Calibrated: 11/11/2015
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.8 (8);

GSM1900 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 19.78 V/m; Power Drift = 0.10 dB
Applied MIF = 3.56 dB
RF audio interference level = 31.95 dBV/m
Emission category: M3

MIF scaled E-field

Grid 1 **M4** **29.63 dBV/m**	Grid 2 **M4** **29.93 dBV/m**	Grid 3 **M4** **29.22 dBV/m**
Grid 4 **M4** **26.08 dBV/m**	Grid 5 **M4** **29.39 dBV/m**	Grid 6 **M4** **29.38 dBV/m**
Grid 7 **M4** **29.55 dBV/m**	Grid 8 **M3** **31.95 dBV/m**	Grid 9 **M3** **31.76 dBV/m**

0 dB = 39.56 V/m = 31.95 dBV/m

15. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client PC Test

Certificate No: ER3-2335_Aug15/2

CALIBRATION CERTIFICATE (Replacement of No: ER3-2335_Aug15)

Object	ER3DV6 - SN:2335
Calibration procedure(s)	QA CAL-02.v8, QA CAL-25.v6 Calibration procedure for E-field probes optimized for close near field evaluations in air
Calibration date:	August 24, 2015

10/1/2015

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	01-Apr-15 (No. 217-02128)	Mar-16
Power sensor E4412A	MY41498087	01-Apr-15 (No. 217-02128)	Mar-16
Reference 3 dB Attenuator	SN: S5054 (3c)	01-Apr-15 (No. 217-02129)	Mar-16
Reference 20 dB Attenuator	SN: S5277 (20x)	01-Apr-15 (No. 217-02132)	Mar-16
Reference 30 dB Attenuator	SN: S5129 (30b)	01-Apr-15 (No. 217-02133)	Mar-16
Reference Probe ER3DV6	SN: 2328	08-Oct-14 (No. ER3-2328_Oct14)	Oct-15
DAE4	SN: 789	16-Mar-15 (No. DAE4-789_Mar15)	Mar-16
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-13)	In house check: Apr-16
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-14)	In house check: Oct-15

	Name	Function	Signature
Calibrated by:	Jeton Kastrati	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: September 22, 2015

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

((

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C, D	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *NORM(f)x,y,z = NORMx,y,z * frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *PAR:* PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- *Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. *VR* is the maximum calibration range expressed in RMS voltage across the diode.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORMx* (no uncertainty required).

Probe ER3DV6

SN:2335

Manufactured: September 9, 2003
Calibrated: August 24, 2015

Calibrated for DASY/EASY Systems
(Note: non-compatible with DASY2 system!)

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu V/(V/m)^2$)	1.65	1.67	1.88	± 10.1 %
DCP (mV)[B]	100.3	99.3	100.2	

Modulation Calibration Parameters

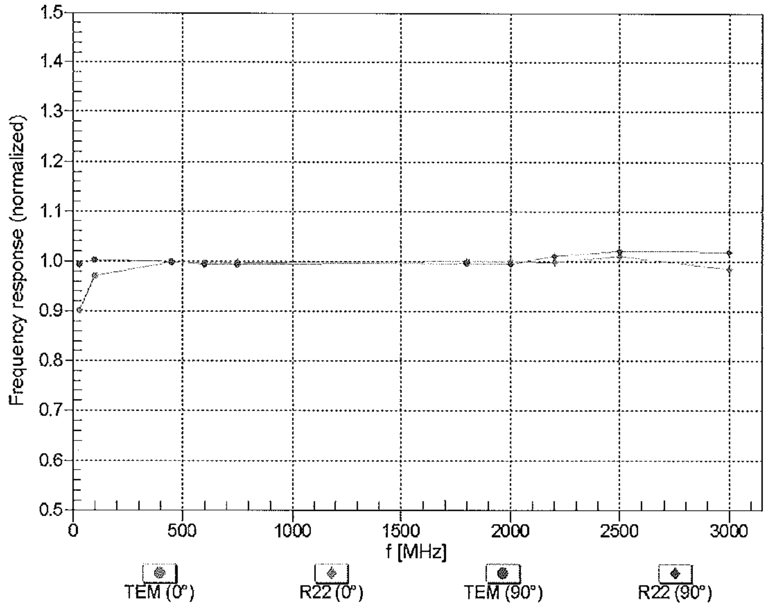
UID	Communication System Name		A dB	B dB$\sqrt{\mu V}$	C	D dB	VR mV	Unc[E] (k=2)
0	CW	X	0.0	0.0	1.0	0.00	203.0	±3.3 %
		Y	0.0	0.0	1.0		160.6	
		Z	0.0	0.0	1.0		203.5	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[B] Numerical linearization parameter: uncertainty not required.
[E] Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

Frequency Response of E-Field

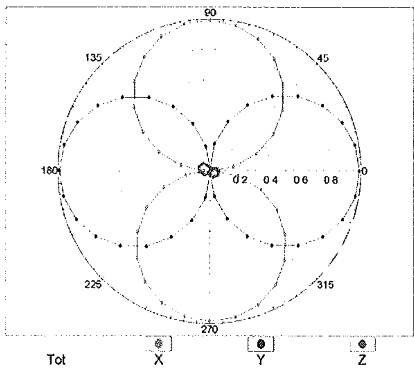
(TEM-Cell:ifi110 EXX, Waveguide: R22)



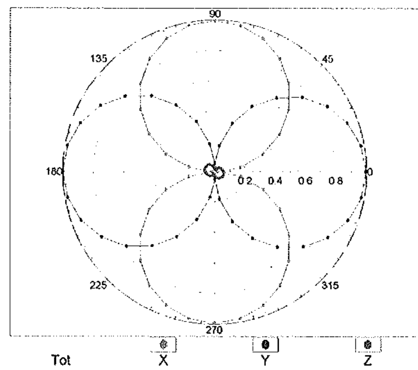
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

Receiving Pattern (ϕ), $\vartheta = 0°$

f=600 MHz,TEM,0°

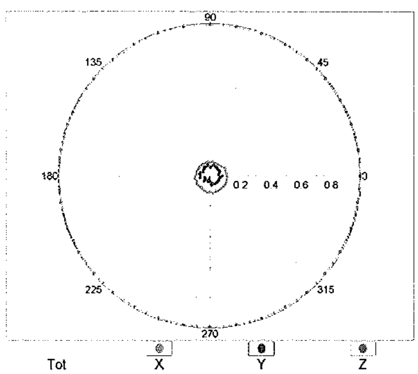


f=2500 MHz,R22,0°

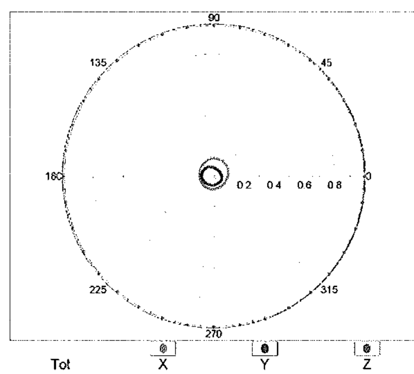


Receiving Pattern (ϕ), $\vartheta = 90°$

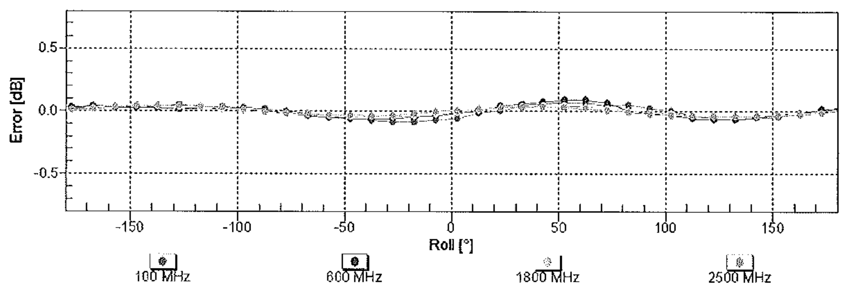
f=600 MHz,TEM,90°



f=2500 MHz,R22,90°

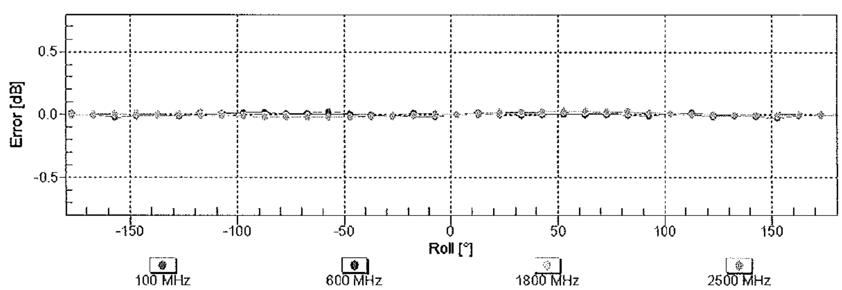


Receiving Pattern (ϕ), ϑ = 0°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

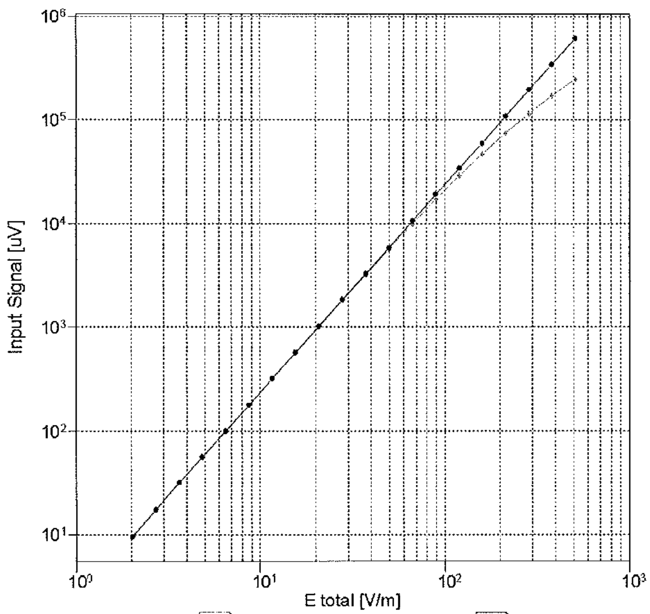
Receiving Pattern (ϕ), ϑ = 90°

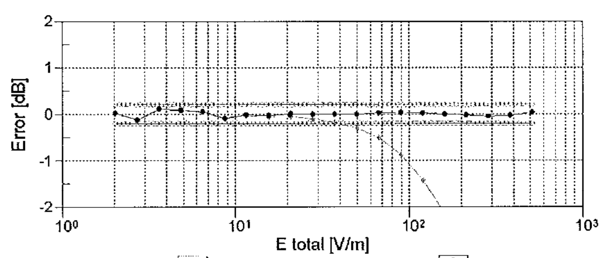


Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Dynamic Range f(E-field)

(TEM cell , f = 900 MHz)

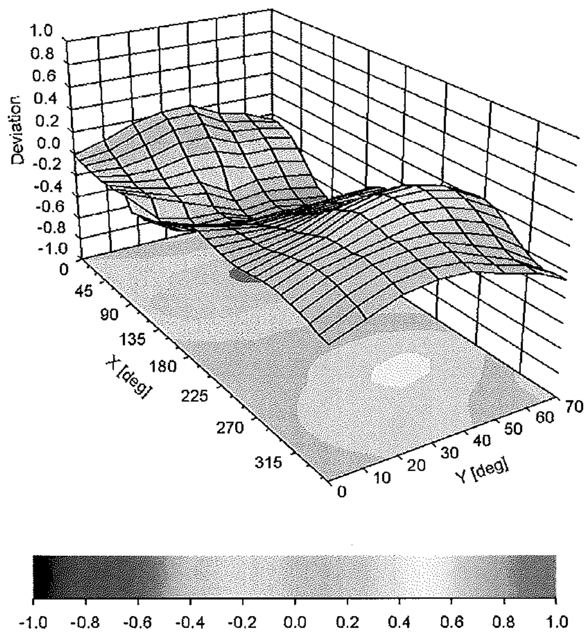




Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Deviation from Isotropy in Air

Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	82.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

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Swiss Calibration Service

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The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client **PC Test**

Certificate No: CD835V3-1003_Feb15

CALIBRATION CERTIFICATE

Object: CD835V3 - SN: 1003

Calibration procedure(s): QA CAL-20.v6
Calibration procedure for dipoles in air

CCV 3/16/15

Calibration date: February 18, 2015

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	07-Oct-14 (No. 217-02020)	Oct-15
Power sensor HP 8481A	US37292783	07-Oct-14 (No. 217-02020)	Oct-15
Power sensor HP 8481A	MY41092317	07-Oct-14 (No. 217-02021)	Oct-15
Reference 10 dB Attenuator	SN: 5047.2 / 06327	03-Apr-14 (No. 217-01921)	Apr-15
Probe ER3DV6	SN: 2336	31-Dec-14 (No. ER3-2336_Dec14)	Dec-15
Probe H3DV6	SN: 6065	31-Dec-14 (No. H3-6065_Dec14)	Dec-15
DAE4	SN: 781	12-Sep-14 (No. DAE4-781_Sep14)	Sep-15

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Sep-14)	In house check: Sep-16
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Sep-14)	In house check: Sep-16
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Sep-14)	In house check: Sep-16
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-14)	In house check: Oct-15
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-13)	In house check: Oct-16

	Name	Function	Signature
Calibrated by:	Leif Klysner	Laboratory Technician	Leif Klysner
Approved by:	Fin Bomholt	Deputy Technical Manager	F. Bomholt

Issued: February 19, 2015

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

References

[1] ANSI-C63.19-2011
American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	107.6 V/m = 40.64 dBV/m
Maximum measured above low end	100 mW input power	106.0 V/m = 40.51 dBV/m
Averaged maximum above arm	100 mW input power	**106.8 V/m ± 12.8 % (k=2)**

Appendix (Additional assessments outside the scope of SCS0108)

Antenna Parameters

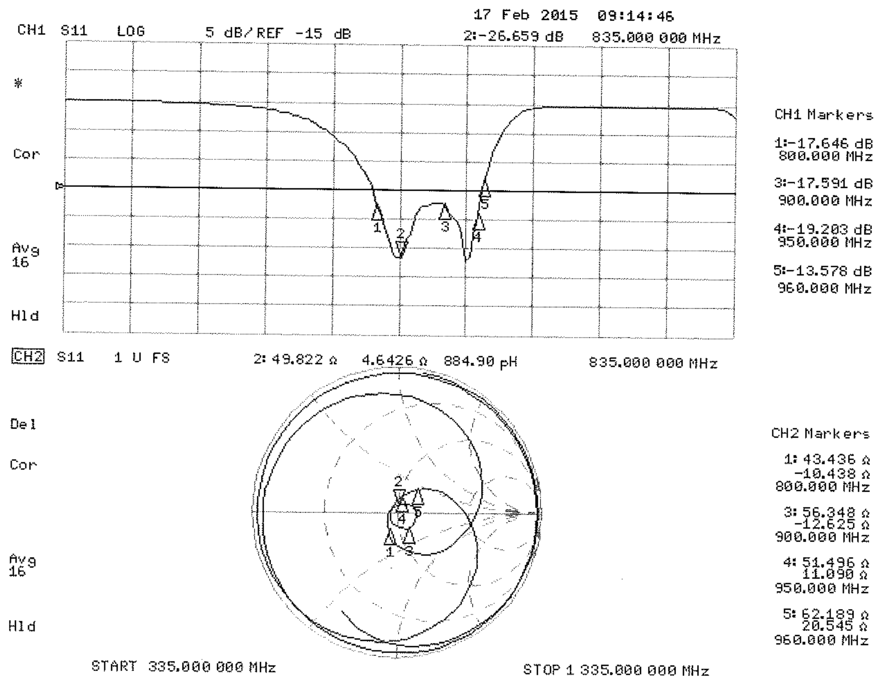
Frequency	**Return Loss**	**Impedance**
800 MHz	17.6 dB	43.4 Ω - 10.4 jΩ
835 MHz	26.7 dB	49.8 Ω + 4.6 jΩ
900 MHz	17.6 dB	56.3 Ω - 12.6 jΩ
950 MHz	19.2 dB	51.5 Ω + 11.1 jΩ
960 MHz	13.6 dB	62.2 Ω + 20.5 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Impedance Measurement Plot



Certificate No: CD835V3-1003_Feb15 Page 4 of 5

DASY5 E-field Result

Date: 17.02.2015

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1003

Communication System: UID 0 - CW ; Frequency: 835 MHz
Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

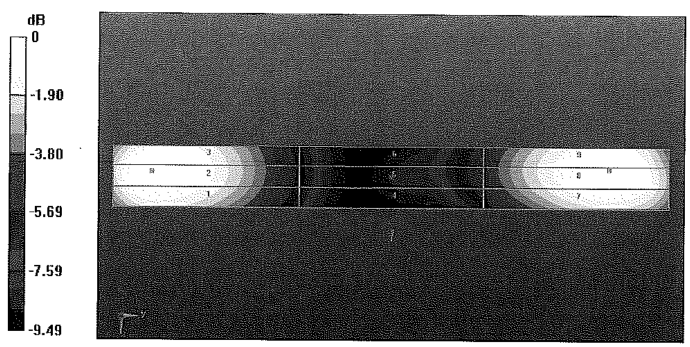
DASY52 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2014;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 12.09.2014
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.8(1222); SEMCAD X 14.6.10(7331)

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1):
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 121.2 V/m; Power Drift = 0.02 dB
Applied MIF = 0.00 dB
RF audio interference level = 40.64 dBV/m
Emission category: M3

MIF scaled E-field

Grid 1 **M3** **40.26 dBV/m**	Grid 2 **M3** **40.64 dBV/m**	Grid 3 **M3** **40.58 dBV/m**
Grid 4 **M4** **35.64 dBV/m**	Grid 5 **M4** **36.04 dBV/m**	Grid 6 **M4** **36.03 dBV/m**
Grid 7 **M3** **40.15 dBV/m**	Grid 8 **M3** **40.51 dBV/m**	Grid 9 **M3** **40.5 dBV/m**



0 dB = 107.6 V/m = 40.64 dBV/m

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S **Schweizerischer Kalibrierdienst**
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Swiss Calibration Service

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The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client **PC Test**

Certificate No: CD1880V3-1137_Feb15

CALIBRATION CERTIFICATE

Object	CD1880V3 - SN: 1137
Calibration procedure(s)	QA CAL-20.v6 Calibration procedure for dipoles in air
Calibration date:	February 17, 2015

CC✓
3/16/15

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
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Power sensor HP 8481A	US37292783	07-Oct-14 (No. 217-02020)	Oct-15
Power sensor HP 8481A	MY41092317	07-Oct-14 (No. 217-02021)	Oct-15
Reference 10 dB Attenuator	SN: 5047.2 / 06327	03-Apr-14 (No. 217-01921)	Apr-15
Probe ER3DV6	SN: 2336	31-Dec-14 (No. ER3-2336_Dec14)	Dec-15
Probe H3DV6	SN: 6065	31-Dec-14 (No. H3-6065_Dec14)	Dec-15
DAE4	SN: 781	12-Sep-14 (No. DAE4-781_Sep14)	Sep-15

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Sep-14)	In house check: Sep-16
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Sep-14)	In house check: Sep-16
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Sep-14)	In house check: Sep-16
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-14)	In house check: Oct-15
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-13)	In house check: Oct-16

	Name	Function	Signature
Calibrated by:	Leif Klysner	Laboratory Technician	Leif Klysner
Approved by:	Fin Bomholt	Deputy Technical Manager	F. Bomholt

Issued: February 19, 2015

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

References

[1] ANSI-C63.19-2011
American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E-field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	98.8 V/m = 39.90 dBV/m
Maximum measured above low end	100 mW input power	93.2 V/m = 39.39 dBV/m
Averaged maximum above arm	100 mW input power	**96.0 V/m ± 12.8 % (k=2)**

Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW input power	90.2 V/m = 39.10 dBV/m
Maximum measured above low end	100 mW input power	89.1 V/m = 38.99 dBV/m
Averaged maximum above arm	100 mW input power	**89.7 V/m ± 12.8 % (k=2)**

Appendix (Additional assessments outside the scope of SCS0108)

Antenna Parameters

Nominal Frequencies

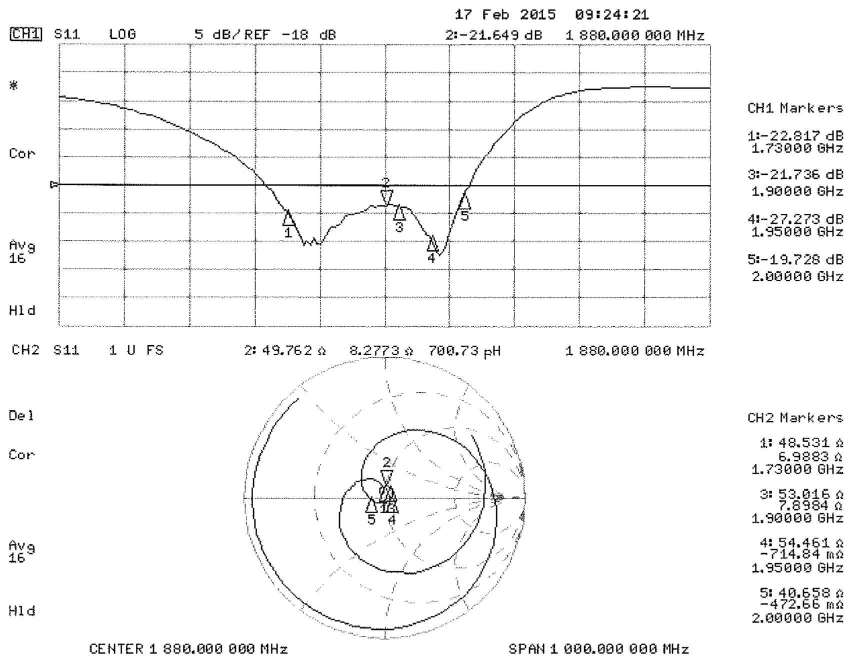
Frequency	Return Loss	Impedance
1730 MHz	22.8 dB	48.5 Ω + 7.0 jΩ
1880 MHz	21.6 dB	49.8 Ω + 8.3 jΩ
1900 MHz	21.7 dB	53.0 Ω + 7.9 jΩ
1950 MHz	27.3 dB	54.5 Ω - 0.7 jΩ
2000 MHz	19.7 dB	40.7 Ω - 0.5 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Impedance Measurement Plot



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DASY5 E-field Result

Date: 17.02.2015

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: UID 0 - CW ; Frequency: 1880 MHz, Frequency: 1730 MHz
Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2014;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 12.09.2014
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.8(1222); SEMCAD X 14.6.10(7331)

Dipole E-Field measurement/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 145.1 V/m; Power Drift = -0.01 dB
Applied MIF = 0.00 dB
RF audio interference level = 39.10 dBV/m
Emission category: M2

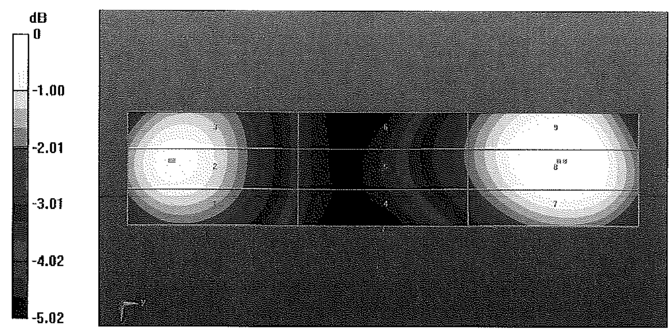
MIF scaled E-field

Grid 1 **M2** **38.62 dBV/m**	Grid 2 **M2** **38.99 dBV/m**	Grid 3 **M2** **38.92 dBV/m**
Grid 4 **M2** **36.52 dBV/m**	Grid 5 **M2** **36.82 dBV/m**	Grid 6 **M2** **36.81 dBV/m**
Grid 7 **M2** **38.84 dBV/m**	Grid 8 **M2** **39.1 dBV/m**	Grid 9 **M2** **39.07 dBV/m**

Dipole E-Field measurement/E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 158.0 V/m; Power Drift = -0.01 dB
Applied MIF = 0.00 dB
RF audio interference level = 39.90 dBV/m
Emission category: M2

MIF scaled E-field

Grid 1 **M2** **39.02 dBV/m**	Grid 2 **M2** **39.39 dBV/m**	Grid 3 **M2** **39.32 dBV/m**
Grid 4 **M2** **37.42 dBV/m**	Grid 5 **M2** **37.87 dBV/m**	Grid 6 **M2** **37.86 dBV/m**
Grid 7 **M2** **39.53 dBV/m**	Grid 8 **M2** **39.9 dBV/m**	Grid 9 **M2** **39.87 dBV/m**



0 dB = 90.20 V/m = 39.10 dBV/m

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16. CONCLUSION

The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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